

STTH100W06C

Datasheet - production data

Turbo 2 ultrafast high voltage rectifier

Features

- Ultrafast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses
- ECOPACK[®]2 compliant component
- Ribbon bonding for more robustness

Description

The STTH100W06CW, uses ST Turbo 2, 600 V technology. It is especially suited to be used for DC/DC and DC/AC converters in secondary stage of MIG/MMA/TIG welding machine. Housed in ST's TO-247, this device offers high power integration for all welding machines and industrial applications.

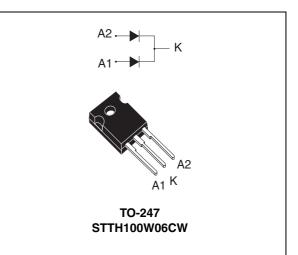


Table 1.Device summary

| Symbol | Value |
|-----------------------|----------|
| I _{F(AV)} | 2 x 50 A |
| V _{RRM} | 600 V |
| t _{rr} (typ) | 55 ns |
| T _j (max) | 175 °C |
| V _F (typ) | 0.92 V |

This is information on a product in full production.

1 Characteristics

Table 2.Absolute ratings (limiting values, at 25 °C, unless otherwise specified,
per diode)

| Symbol | Paramete | Value | Unit | | |
|---------------------|---|------------------------|------------|-----|---|
| V _{RRM} | Repetitive peak reverse voltage | 600 | V | | |
| I _{F(RMS)} | Forward rms current | 75 | А | | |
| 1 | Average forward current, $\delta = 0.5$ | $T_c = 135 \text{ °C}$ | | 50 | А |
| ^I F(AV) | Average forward current, $\delta = 0.5$ | $T_c = 120^{\circ}C$ | Per device | 100 | ~ |
| I _{FSM} | Surge non repetitive forward current | 360 | А | | |
| T _{stg} | Storage temperature range | -65 to + 175 | °C | | |
| Тj | Maximum operating junction tempera | | + 175 | °C | |

Table 3.Thermal resistance

| Symbol | Parameter | | Value | Unit |
|----------------------|------------------|-----------|--------|-------|
| P | Junction to case | Per diode | 0.55 | °C/W |
| R _{th(j-c)} | | Total | 0.35 | C / W |
| R _{th(c)} | Coupling | 0.15 | °C / W | |

When diodes 1 and 2 are used simultaneously:

 $T_{j}(diode 1) = P(diode 1) \times R_{th(j-c)}(per diode) + P(diode 2) \times R_{th(c)}$

| | State electrical characteristics (per diode) | | | | | | |
|-------------------------------|---|-------------------------|-----------------------------------|------|------|------|------|
| Symbol | Parameter | Test conditions | | Min. | Тур. | Max. | Unit |
| I _B ⁽¹⁾ | Povoroo lookogo ourront | T _j = 25 °C | V _R = V _{RRM} | | | 20 | |
| 'R`´ | I _R ⁽¹⁾ Reverse leakage current | T _j = 125 °C | | | 20 | 200 | μA |
| | | $T_j = 25 \text{ °C}$ | I _F = 50A | | | 1.45 | |
| V _F ⁽²⁾ | ⁽²⁾ Forward voltage drop | T _j = 150 °C | 1F - 30A | | 0.92 | 1.15 | v |
| ¥F`´ | | T _j = 25 °C | I _F = 100 A | | | 1.65 | |
| | | T _j = 150 °C | 1 _F = 100 A | | 1.15 | 1.45 | |

 Table 4.
 Static electrical characteristics (per diode)

1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

2. Pulse test: t_p = 380 µs, δ < 2%

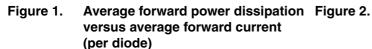
To evaluate the conduction losses use the following equation:

 $P = 0.85 \text{ x } I_{F(AV)} + 0.006 I_{F}^{2}(RMS)$



| Symbol | Parameter | Test conditions | | Min. | Тур. | Max. | Unit |
|---------------------|--------------------------|-------------------------|--|------|------|------|------|
| I _{RM} | Reverse recovery current | | | | 30 | 40 | А |
| Q _{RR} | Reverse recovery charge | T _j = 125 °C | I _F = 50 A, V _R = 400 V dI _F /dt = -200 A/μs | | 3700 | | nC |
| S _{factor} | Softness factor | | | | 0.3 | | |
| t _{rr} | Reverse recovery time | T _j = 25 °C | I _F = 1 A, V _R = 30 V dI _F /dt = -100 A/μs | | 55 | 75 | ns |
| t _{fr} | Forward recovery time | T _j = 25 °C | 5 °C I _F = 50 A, V _{FR} = 1.0V | | | 200 | ns |
| V _{FP} | Forward recovery voltage | T _j = 25 °C | dI _F /dt = 200 A/µs | | 1.3 | 2 | V |

 Table 5.
 Dynamic electrical characteristics (per diode)





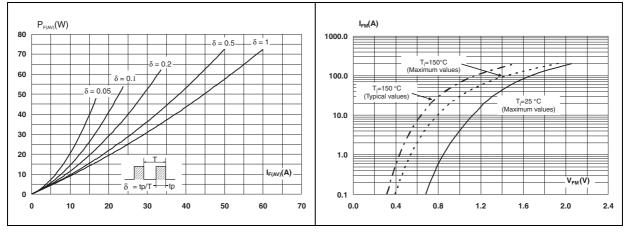
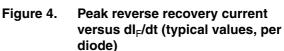
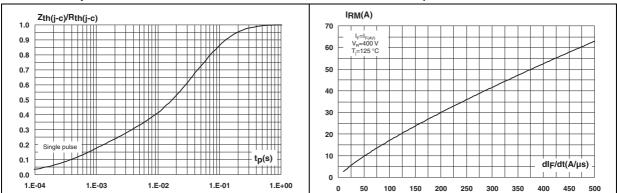


Figure 3. Relative variation of thermal Figure 3. Inpedance junction to case versus pulse duration

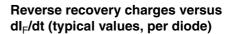




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dIF/dt(A/µs)

Figure 5. Reverse recovery time versus dl_F/dt Figure 6. (typical values, per diode)



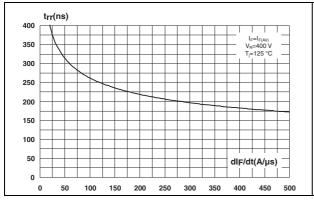
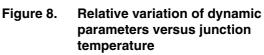


Figure 7. Reverse recovery softness factor versus dl_F/dt (typical values, per diode)



Q_{RR}(nC)

I_F=I_{F(AV)} V_R=400 V T_i=125 °C

7000

6000

5000

4000

3000

2000

1000

0

0 50 100 150 200 250 300 350 400 450 500

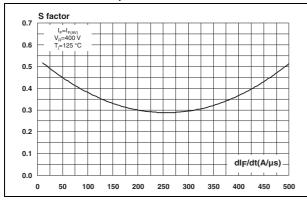


Figure 9. Transient peak forward voltage versus dl_F/dt (typical values, per diode)

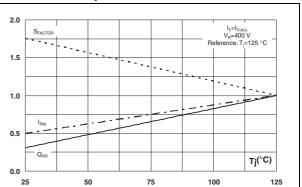


Figure 10. Forward recovery time versus dl_F/dt (typical values, per diode)

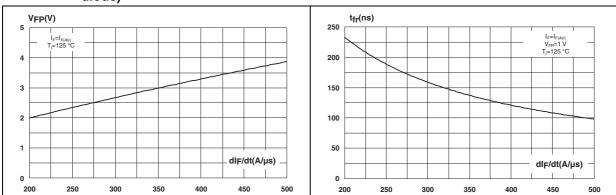
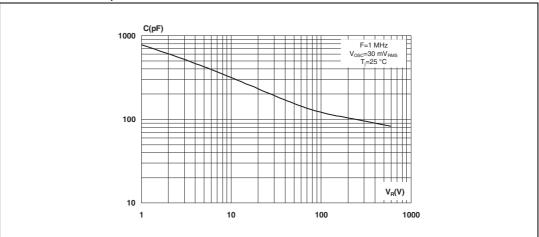




Figure 11. Junction capacitance versus reverse voltage applied (typical values, per diode)





2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N·m (1.0 N·m maximum)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK[®] is an ST trademark.

Table 6. TO-247 dimensions

| | | | | | | Dimer | nsions | | | |
|--|---|------|-------------------|-------|----------|---------|--------|-------|----------|----|
| | | | Ref. | Mi | illimete | ers | Inches | | | |
| | | | | Min. | Тур. | Max. | Min. | Тур. | Max. | |
| E S S R R Heat-sink plane | | | А | 4.85 | | 5.15 | 0.191 | | 0.203 | |
| | | A1 | 2.20 | | 2.60 | 0.086 | | 0.102 | | |
| | b | 1.00 | | 1.40 | 0.039 | | 0.055 | | | |
| | | b1 | 2.00 | | 2.40 | 0.078 | | 0.094 | | |
| | | | b2 | 3.00 | | 3.40 | 0.118 | | 0.133 | |
| D S OR | | | с | 0.40 | | 0.80 | 0.015 | | 0.031 | |
| L2 | | | D ⁽¹⁾ | 19.85 | | 20.15 | 0.781 | | 0.793 | |
| | | | Е | 15.45 | | 15.75 | 0.608 | | 0.620 | |
| $L \downarrow \downarrow$ | | | е | 5.30 | 5.45 | 5.60 | 0.209 | 0.215 | 0.220 | |
| $\begin{array}{c} & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ \end{array}$ | | | L | 14.20 | | 14.80 | 0.559 | | 0.582 | |
| e | | | L1 | 3.70 | | 4.30 | 0.145 | | 0.169 | |
| | | | | L2 | 1 | 8.50 ty | p. | 0 | .728 typ | Э. |
| | | | ØP ⁽²⁾ | 3.55 | | 3.65 | 0.139 | | 0.143 | |
| | | | ØR | 4.50 | | 5.50 | 0.177 | | 0.217 | |
| | | | S | 5.30 | 5.50 | 5.70 | 0.209 | 0.216 | 0.224 | |

1. Dimension D plus gate protrusion does not exceed 20.5 mm

2. Resin thickness around the mounting hole is not less than 0.9 mm



3 Ordering information

Table 7.Ordering information

| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
|---------------|--------------|---------|--------|----------|---------------|
| STTH100W06CW | STTH100W06CW | TO-247 | 4.46 g | 50 | Tube |

4 Revision history

Table 8.Document revision history

| Date | Revision | Changes |
|-------------|----------|--------------|
| 05-Oct-2012 | 1 | First issue. |



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